# **Schottky Barrier Diode**

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

#### **Features**

Extremely Fast Switching Speed

Extremely Low Forward Voltage – 0.35 V (Typ) @  $I_F = 10 \text{ mAdc}$ 

These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



# ON Semiconductor®

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# 30 VOLT SCHOTTKY BARRIER DETECTOR AND SWITCHING DIODE



# MAXIMUM RATINGS (T<sub>J</sub> = 125 C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	$V_R$	30	V
Forward Power Dissipation @ T <sub>A</sub> = 25 C Derate above 25 C	P <sub>F</sub>	200 1.6	mW mW/ C
Forward Current (DC)	Ι <sub>Ε</sub>	200 Max	mA
Non-Repetitive Peak Forward Current, t <sub>p</sub> < 10 msec	I <sub>FSM</sub>	600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	I <sub>FRM</sub>	300	mA
Junction Temperature	TJ	-55 to 125	С
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	С

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## MARKING DIAGRAM



SOT-323 CASE 419



B4 = Device Code

M = Date Code\*

Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

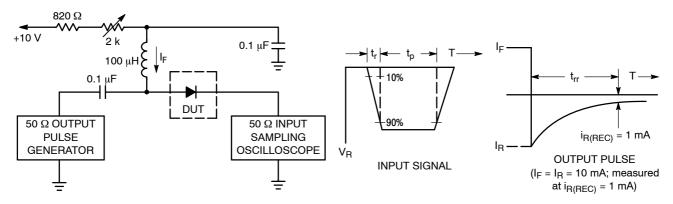
Device	Package	Shipping <sup>†</sup>
BAT54WT1G	SOT-323 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>Date Code orientation may vary depending upon manufacturing location.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25 C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \mu A)$	V <sub>(BR)R</sub>	30	-	-	V
Total Capacitance (V <sub>R</sub> = 1.0 V, f = 1.0 MHz)	C <sub>T</sub>	-	7.6	10	pF
Reverse Leakage (V <sub>R</sub> = 25 V)	I <sub>R</sub>	-	0.5	2.0	μAdc
Forward Voltage (I <sub>F</sub> = 0.1 mAdc)	V <sub>F</sub>	-	0.22	0.24	Vdc
Forward Voltage (I <sub>F</sub> = 30 mAdc)	V <sub>F</sub>	-	0.41	0.5	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	-	0.52	0.8	Vdc
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}, Figure 1)$	t <sub>rr</sub>	-	-	5.0	ns
Forward Voltage (I <sub>F</sub> = 1.0 mAdc)	V <sub>F</sub>	-	0.29	0.32	Vdc
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	-	0.35	0.40	Vdc



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (IF) of 10 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10 mA.
- 3. t<sub>p</sub> » t<sub>ri</sub>

Figure 1. Recovery Time Equivalent Test Circuit

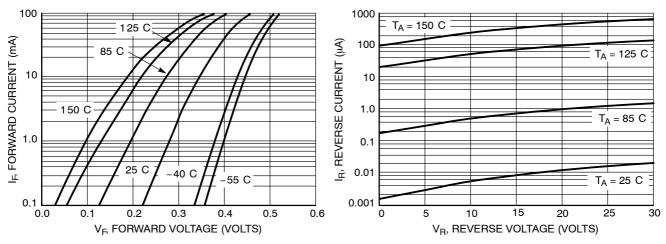


Figure 2. Forward Voltage

Figure 3. Leakage Current

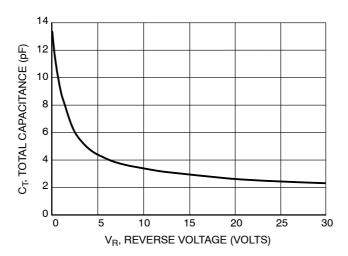
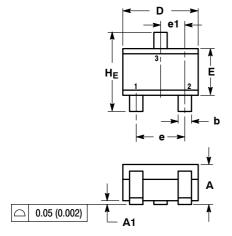


Figure 4. Total Capacitance

## PACKAGE DIMENSIONS

## SOT-323 (SC-70) CASE 419-04 **ISSUE N**





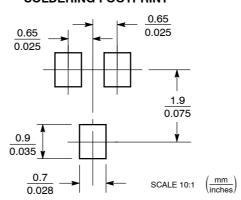
#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	MOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF 0.028 REF			=		
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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